PCI	Number:	202212	16005	6005.2 PC			N Date: December 21, 2022				
Titl	Qualit	ication of n	iew Fa	I Fab site (RFAB) using qualified Process Technology, Die Revision							
	and n	ew Assemb	ly & fi	nal test site (MLA)	for select	device	S				
Cus	stomer Conta	ct:	PCI	<u>N Manager</u>		Dept:		Quality Services			
Proposed 1 st Ship Date:				18, 2023	Sample accepte			Jan 20, 2023*			
*Sa	mple reques	sts receive	d afte	after Jan 20, 2023 will not be supported.							
Cha	ange Type:										
\boxtimes	Assembly Sit	е		Assembly Process			Assei	mbly Materials			
\boxtimes	Design			Electrical Specification			Mech	anical Specification			
	Test Site		\square	Packing/Shipping/	/Labeling		Test	Process			
□ Wafer Bump Site				Wafer Bump Material			Wafe	er Bump Process			
🛛 Wafer Fab Site				☑ Wafer Fab Materials			Wafe	r Fab Process			
				Part number change							
					21.0						

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (RFAB, LBC9) and new Final test site & assembly site (MLA) for selected devices as listed below in the product affected section:

C	urrent Fab Site	3	Additional Fab Site				
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter		
SFAB	IMP-PWR2	150 mm	RFAB	LBC9	300 mm		

The die was also changed as a result of the process change.

The pin one designator will be changing:

	Current	New
Pin one ID	Stripe	Dot

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
🛛 No Change	🛛 No Change	🛛 No Change	🛛 No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City	
SH-BIP-1	SHE	USA	Sherman	
RFAB	RFB	USA	Richardson	

TI Malaysia	MLA	MYS	Kuala Lumpur
TI Mexico	MEX	MEX	Aguascalientes
Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City

Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]
A	Α

Sample product shipping label (not actual product label)



The datasheets will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history shown below. The links to the revised datasheets are available in the table below.

-4	Texas Instru	JMENTS	UCC28C40	Q1, UCC28C	41-Q1, L	JCC28C4	C28C44-Q1, UCC28C45-Q1 2009 – REVISED NOVEMBER 2022
							-

- Added V_{REF} maximum continuous voltage from external circuitry in Recommended Operating Conditions.....4

Product Folder	Current Datasheet Number	New Datasheet Number	Link to full datasheet
UCC28C4x-Q1	SLUSA12F	SLUSA12G	http://www.ti.com/product/UCC28C40-Q1
Product Affected			

Product Affected:

UCC28C40QDRQ1	UCC28C42QDRQ1	UCC28C44QDRQ1	UCC28C45QDRQ1							
UCC28C41QDRQ1	UCC28C43QDRQ1									
For alternate parts with similar or improved performance, please visit the product page on TI.com										

II Information Selective Disclosure

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Toledo Automotive C4Y Change devices PG1.1 Approve Date 21-OCTOBER -2022

Product Attributes

Attributes	Qual Device:	Qual Device:	Qual Device:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:
Attributes	UCC28C44QDRQ1	UCC28C43QDRQ1	UCC28C41QDRQ1	LM74700QDBVRQ1	LM74700QDBVRQ1	UCC28C56HQDRQ1	SN65HVD1781AQDRQ1	UCC28C52QDRQ1
Automotive Grade Level	Grade 1	Grade 1						
Operating Temp Range (C)	-40 to 125	-40 to 125						
Product Function	Power Management	Interface	Power Management					
Wafer Fab Supplier	RFAB	RFAB	RFAB	RFAB	RFAB	RFAB	DP1DM5	RFAB
Assembly Site	MLA	MLA	MLA	UTL2	UTL2	MLA	MLA	MLA
Package Group	SOIC	SOIC	SOIC	SOT	SOT	SOIC	SOIC	SOIC
Package Designator	D	D	D	DBV	DBV	D	D	D
Pin Count	8	8	8	6	6	8	8	8

Г

QBS: Qual By Similarity
 Qual Device UCC28C44QDRQ1 is qualified at MSL1 260C
 Qual Device UCC28C43QDRQ1 is qualified at MSL1 260C
 Qual Device UCC28C41QDRQ1 is qualified at MSL1 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration		Qual Device: UCC28C43QDRQ1	Qual Device: UCC28C41QDRQ1				QBS Reference: SN65HVD1781AQDRQ1
Test Group	Test Group A - Accelerated Environment Stress Tests													
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step			-	-	-	No Fails	No Fails
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours		-	-	-	-	1/77/0	3/231/0

TDDB D2 JESD36 - Image: The construction of the constru															
Yet Specify Specify Yet Specify Specify <t< td=""><td>AC/UHAST</td><td>A3</td><td>JESD22- A102/JEDEC JESD22-</td><td>3</td><td>77</td><td>Autoclave</td><td>121C/15psig</td><td>96 Hours</td><td>-</td><td>-</td><td>-</td><td>-</td><td>-</td><td>1/77/0</td><td>3/231/0</td></t<>	AC/UHAST	A3	JESD22- A102/JEDEC JESD22-	3	77	Autoclave	121C/15psig	96 Hours	-	-	-	-	-	1/77/0	3/231/0
NameNameNameNameNameNameNameNameNameNameNameNameNamePTCSSSSPTCadd250SolvesSol	rc	A 4	JESD22- A104 and	3	77	Temperature Cycle	-65C/150C	500 Cycles	-	-	-	-	-	1/77/0	3/231/0
PTCAsSigney AsAAsPTCDallaseCourse As	IC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-		-	-		-	1/5/0	1/5/0
HTSLModSignatureSignatu	тс	A5	JESD22-	1	45	PTC	-40/125C		-	-	-			-	-
HTSLAbSeg2b1AbStegser1AbStegser1AbSteggerAbAbStegger </td <td>ITSL</td> <td>A6</td> <td>JESD22-</td> <td>1</td> <td>45</td> <td>Temperature</td> <td>150C</td> <td></td> <td>-</td> <td>-</td> <td>-</td> <td>-</td> <td>-</td> <td>1/77/0</td> <td>-</td>	ITSL	A6	JESD22-	1	45	Temperature	150C		-	-	-	-	-	1/77/0	-
Interface provided Lifetime Simulation Test:Image: Solution Test:Image: Solutio	ITSL	A6	JESD22-	1	45	Temperature	175C			-	-				1/45/0
HTOLBLALGOR-LIT7Life Test125CMoore- Accord- A															
N1Ce Bit Alfred I Defende Alfred Hours I completed Perroperson I completed Perroper			JEDEC					1000							
HTOLB1AlsoAlsoAlor	ITOL	B1	A108	1	77	Life Test	125C	Hours	-	-	-	-	-	1/77/0	
HTOLB1ASCO101011/1 Test150CAUO100010001000100001000000100000001000000000100000000000001000000000000000000000000000000000000	ITOL	B1	JESD22- A108	1	77	Life Test	140C	480 Hours	-	-	-	•	-		•
ELP R R I <thi< th=""> I I <thi< th=""></thi<></thi<>	ITOL	81	JESD22- A108	1	77		150C	Hours			-	1/77/0	2/154/0		
WBSC1AEC Q100- 01130Wire Bond ShearMinimum of Society Signation devices 30 Cpk>167Wires	LFR	B2		1	77		150C			-	-	-	3/2400/0		•
WBSC1AEC Q100110WISolWires on this speet on this	lest Group	C - Pack	age Assembly	Integrity	Tests										
WEPC2Mirels Stores130Mirels ond PuilMirels ond Puil	VBS	C1	AEC Q100- 001	1	30		devices, 30 wires	Wires	-	-	-	-	-	3/90/0	3/90/0
SD C3 JESD222- 1 15 PB Solderability Coverage - - - - - - 1250 SD C3 JEDEC B102 1 15 PB Free Solderability Optimized Coverage - - - - - - - 1250 SD C3 JEDEC B100 and B100 and B100 and B100 and B100 and 1 DB -Free Solderability Optimized Coverage Coverage - - - - - - - 1250 PD C4 JEDEC B100 and B100 and B100 and B100 and 1 D1 DPH vical B100 and B100 and Cpk-1.67 Coverage Coverage <td>VBP</td> <td>C2</td> <td></td> <td>1</td> <td>30</td> <td>Wire Bond Pull</td> <td>devices, 30 wires</td> <td>Wires</td> <td>-</td> <td>-</td> <td>-</td> <td></td> <td>-</td> <td>3/90/0</td> <td>3/90/0</td>	VBP	C2		1	30	Wire Bond Pull	devices, 30 wires	Wires	-	-	-		-	3/90/0	3/90/0
SD C3 JESD222- 1 15 Porter bolic point for bolic poi	5D	СЗ	JESD22-	1	15	PB Solderability	>95% Lead Coverage	-	-	-	-	-	-	1/15/0	-
PD C4 BSD022- BLD0 and BL08 1 10 Physical Dimensions Cpk>1.67 - - - - - - - 3300 Test Corrup EM D1 JESD61 - 1 10 Physical Dimensions Cpk>1.67 - - - - - - - 3300 Test Corrup EM D1 JESD61 - - - Completed Per Process Completed Per Proce	5D	СЗ	JESD22-	1	15	PB-Free Solderability			-	-	-	-	-	1/15/0	
EM D1 JESD61 - Electromigration - Completed Per Process	°D	C4	JESD22- B100 and	1	10	Physical Dimensions	Cpk>1.67				-		-	3/30/0	3/30/0
EM D1 JESD61 - Electronigration - Process Process Requirements Process Process Requirements Process Process Requirements Onlighted Per Process Requirements Completed Per Process Technology Requirements Completed Per Process Technology Requi	fest Group	D - Die F	abrication Relia	ability Te	sts										
TDDB D2 JESD35 - Dependent Dielectic - Process Process Process Process <td>EM</td> <td>D1</td> <td>JESD61</td> <td>-</td> <td>-</td> <td>Electromigration</td> <td></td> <td></td> <td>Process Technology</td> <td>Process Technology</td> <td>Process Technology</td> <td>Process Technology</td> <td>Process Technology</td> <td>Process Technology</td> <td>Completed Per Process Technology Requirements</td>	EM	D1	JESD61	-	-	Electromigration			Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Completed Per Process Technology Requirements
HCI D3 JESD80.8 - Hot Carrier Injection - Process Process Process Process Process Completed Per Completed Per Completed Per Completed Per Process Technology Requirements Requ	DDB	D2	JESD35			Dependent Dielectric			Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Completed Per Process Technology Requirements
	СІ	D3	JESD60 & 28						Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Completed Per Process Technology Requirements
	BTI	D4	-		-	Temperature			Technology	Technology	Technology	Process Technology	Process Technology	Process Technology	Completed Per Process Technology Requirements
Requirements Requi			-		-	Stress Migration			Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Process Technology	Completed Per Process Technology Requirements
Test Group E - Electrical Verification Tests	est Group I			Tests											
ESD E2 AEC Q100- 1 3 ESD HEM - 2500 1/3/0 1/3/0			002					Volts					-		
AEC 0100. 2000	SD	E3	011	1	3	ESD CDM	-	Volts	1/3/0	•	-	•	-	1/3/0	-
	J	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	•	1/6/0	-	-	-	-	1/6/0	-
ESD ES 011 C 1 S ESD CM - Voits 130 - C 1 S - C 1 S ESD CM - 150 -			AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold		1/30/0	1/30/0	1/30/0	-	-	3/90	
ES 61 61 61 63 ESD CUM - Volte J30 - - - - - - J30 - - - - J30 - - - - J30 - - - - - - - J30 - J30 - - - - - J30 - - - - - - J30 - J30 - - - - - J30 - J30 <td>dditional T</td> <td>ests</td> <td></td>	dditional T	ests													
ESD ESD OI1 I I IS ESD CDM - Voits JSIO - - - - ISIO LU E4 AEC Q100- 000 1 6 Latch-Up Per AEC Q100-004 - J60 - - - - - J60 ED E5 AEC Q100- 000 3 30 Electrical Distributions Cpk>167 Room, hot, - J300 J300 J300 - - 390			Test Spec	Min Lot	ssi				Qual Device	Qual Device					

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
 The following are equivalent HTSL options per JESD47 : 55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
 Grade 1 (or Q): -40C to +125C
 Grade 2 (or T): -40C to +105C
 Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold : HTOL, ED
 Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
 Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-NPD-2206-074

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail				
WW Change Management Team	<u>PCN ww admin team@list.ti.com</u>				

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